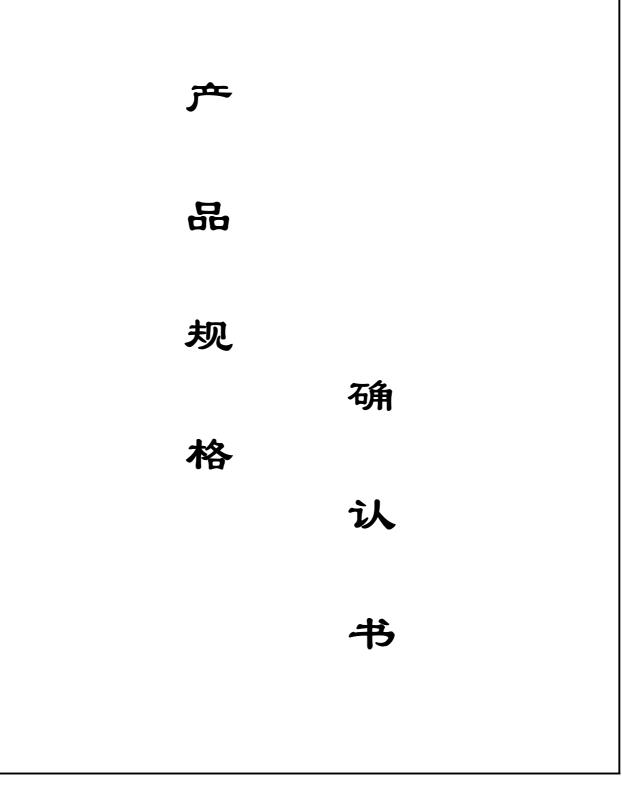
# FR3X SERIES

**SURFACE MOUNT FAST RECOVERY RECTIFIER** 



# FR3A THRU FR3M

## SURFACE MOUNT FAST RECOVERY RECTIFIER

REVERSE VOLTAGE: FORWARD CURRENT: 50 to 1000 VOLTS 3.0 AMPERE

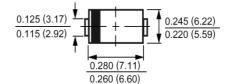


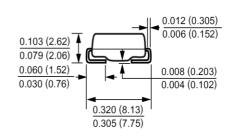
- $\cdot$  For surface mounted applications
- $\cdot$  Low profile package
- · Built-in strain relief
- $\cdot$  Easy pick and place
- $\cdot$  Fast Recovery times for high efficiency
- $\cdot$  Plastic package has Underwriters Laboratory
- Flammability Classification 94V-O
- $\cdot$  High temperature soldering : 260°C /10 seconds at terminals

#### MECHANICAL DATA

Case: Molded plastic, DO-214AB(SMC) Terminals: Solder plated, solderable per MIL-STD-750, method 2026 guaranteed Polarity: Color band denotes cathode end Packaging: 16mm tape per EIA STD RS-481 Weight: 0.007 ounce, 0.21 gram

### DO214-AB(SMC)





Dimensions in inches and (millimeters)

#### Maximum Ratings and Electrical Characteristics

Ratings at 25C ambient temperature unless otherwise specified. Single phase, half wave,  $60H_z$ , resistive or inductive load. For capacitive load, derate current by 20%.

	Symbols	FR3A	FR3B	FR3D	FR3G	FR3J	FR3K	FR3M	Units
Maximum Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current at T <sub>L</sub> =75C	I <sub>(AV)</sub>	3.0							Amp
Peak Forward Surge Current,									
8.3ms single half-sine-wave	I <sub>FSM</sub>	I <sub>FSM</sub> 100							Amp
superimposed on rated load (JEDEC method)									
Maximum Forward Voltage at 3.0A	V <sub>F</sub>	1.3							Volts
Maximum Reverse Current at T <sub>A</sub> =25C	T	5.0							μАтр
at Rated DC Blocking Voltage T <sub>A</sub> =125C	I <sub>R</sub>	300							
Typical Junction Capacitance (Note 1)	CJ	60							pF
Typical Thermal Resistance (Note 2)	R <sub>0JA</sub>	50 15							C/W
	R <sub>0JL</sub>								
Maximum Reverse Recovery Time (Note 3)	T <sub>RR</sub>		1:	50		250	5	00	nS
Operating Junction Temperature Range	TJ	-55 to +150							с
Storage Temperature Range	Tst	-55 to +150							С

#### NOTES:

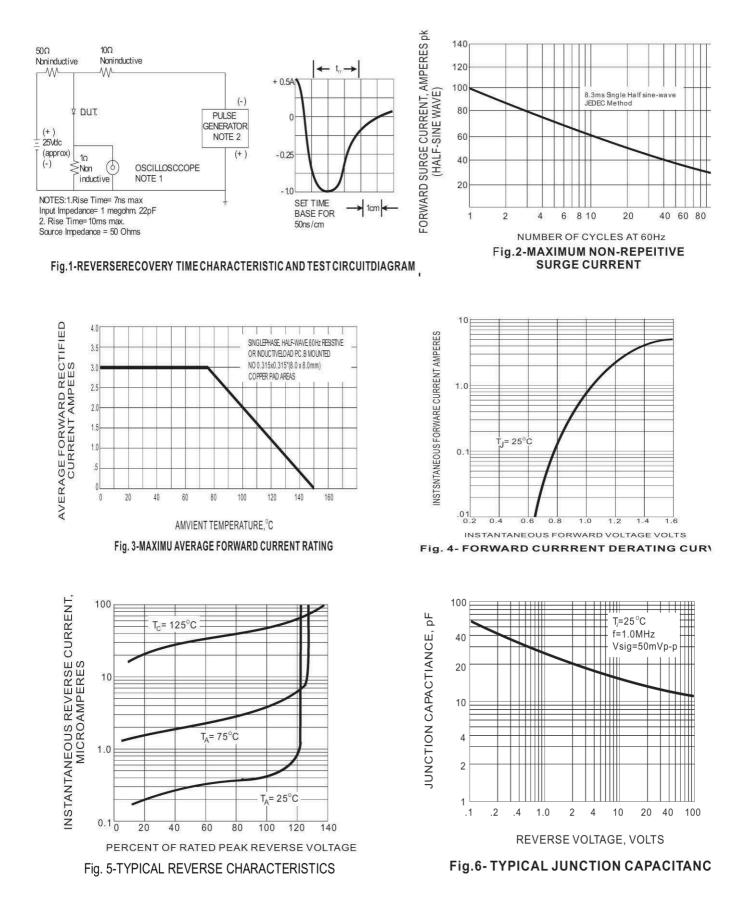
1- Measured at 1  $MH_Z$  and applied reverse voltage of 4.0 VDC.

2- Thermal resistance from junction to ambient and from junction to lead mounted on P.C.B. with 0.3 x 0.3" (8.0 x 8.0mm) copper pad areas

3- Reverse Recovery Test Conditions:  $I_F$ =.5A,  $I_R$ =1A,  $I_{RR}$ =.25A.



### **RATINGS AND CHARACTERISTIC CURVES**



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